

#### **FEATURES AND BENEFITS**

- Sensitivity with B<sub>OP</sub> range: 9 to 70 G
- Ultra-low power consumption: ~110 nA @  $V_{DD}$  = 1.8 V and  $f_S$  = 2 Hz
- Supply voltage range: 1.7 to 5.5 V
- Sensor polarity: omnipolar
- Digital CMOS outputs:
  - Push-pull
  - · Open drain
- Undervoltage lockout (UVLO)
- · Package options:
  - 3-lead SOT23
  - 4-lead LGA, 1.45 mm × 1.45 mm × 0.44 mm

#### **APPLICATIONS**

- IoT devices
- Smartphones, tablets, and laptops
- · Door or lid closure
- · Reed switch replacement
- Tamper-proofing for utility smart meters
- Fluid level sensing/detection
- · Proximity detection
- · Motor controllers
- Gimbals for camera systems in drones/UAVs
- Industrial machinery/robots
- · Medical devices

#### DESCRIPTION

The CT813x series of omnipolar tunnel magnetoresistance (TMR) digital switches are designed for consumer and industrial applications. The devices are based on Allegro patented XtremeSense<sup>TM</sup> TMR technology with integrated CMOS process to provide a monolithic solution for superior sensing performance. The CT813x digital switches offer stable magnetic operation over the operating temperature range.

This product family has very low power consumption—as low as 110 nA—which is ideal for battery-operated products where minimal current consumption is required. The devices support magnetic fields down to 9 G for applications where there is a large air gap requirement.

For applications that require a very small form factor and low profile, the CT813x is assembled in a 4-lead LGA package. They are also available in an industry-standard 3-lead SOT-23 package to support high-volume manufacturing for industrial markets.

#### **PACKAGE**



Not to scale. 4-lead LGA package not shown.

#### **FUNCTIONAL BLOCK DIAGRAMS**

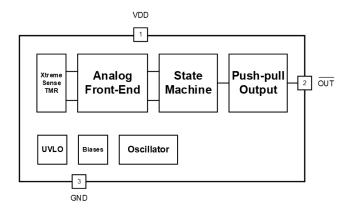


Figure 1: CT8132 with Push-Pull Output Block Diagram for 3-Lead SOT23 Package

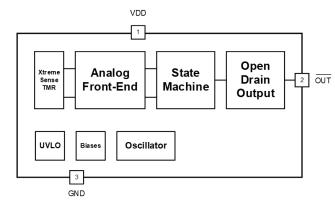


Figure 2: CT8131 with Open Drain Output Block Diagram for 3-Lead SOT23 Package

# **Integrated Omnipolar TMR Digital Switches**

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#### **SELECTION GUIDE**

Part Number	Operating Temp Range (°C)	Sensor Type	Output	B <sub>OP</sub> (G)	B <sub>RP</sub> (G)	f <sub>S</sub>	Package	Packing				
CT8131BV-IL4	-40 to 85	Omenimelen	On an Dunin	±30	±20	2 Hz	4-lead LGA	Tana and Daal				
CT8131BV-HL4	-40 to 125	Omnipolar	Open Drain	±30	±20	2 112	4-lead LGA	Tape and Reel				
CT8131BV-IS3	-40 to 85	Omnipolar	Open Drain	±30	±20	2 Hz	3-lead SOT23	Tape and Reel				
CT8131BV-HS3	-40 to 125	Ommpolar	Орен Бташ	130	120	2 112	3-lead 30123	Tape and Reel				
CT8132BH-IL4	-40 to 85	Omnipolar	Push-Pull	±30	±20	10 kHz	4-lead LGA	Tape and Reel				
CT8132BH-HL4	-40 to 125	Ommpolar	FuSII-FuII	130	120	TU KHZ	4-lead LGA	Tape and Reel				
CT8132BH-IS3	-40 to 85	Omnipolar	Push-Pull	±30	±20	10 kHz	3-lead SOT23	Tape and Reel				
CT8132BH-HS3	-40 to 125	Ommpolar	FuSII-FuII	±30	120	TUKITZ	3-lead 30123	Tape and Neel				
CT8132BL-IS3	-40 to 85	Omnipolar	Push-Pull	±30	±20	250 Hz	3-lead SOT23	Tape and Reel				
CT8132BL-HS3	-40 to 125	Ommpolar	FuSII-FuII	130	120	250 円2	3-lead 30123	Tape and Reel				
CT8132BV-IL4	-40 to 85	Omnipolar Push-Pu	Push-Pull	±30	±20	2 Hz	4-lead LGA	Tape and Reel				
CT8132BV-HL4	-40 to 125	Ommpolar	Jiai Fusii-Fuii	130	120	2112	4-ICAG EGA	Tape and Reel				
CT8132BV-IS3	-40 to 85	Omningler Du	Omnipolar	Push-Pull	±30	±20	2 Hz	3-lead SOT23	Tape and Reel			
CT8132BV-HS3	-40 to 125	Ommpolar	Pusn-Pull	rusii-ruii	i uəii-i uli	i usii-i uli	i doii-i uli		120	2112	3-lead 30123	Tape and Reel
CT8132DM-IS3	-40 to 85	Omnipolar	Push-Pull	±15	±10	2.5 kHz	3-lead SOT23	Tape and Reel				
CT8132DM-HS3	-40 to 125	Ommpolar	FuSII-FuII	±13	110	2.5 KHZ	3-lead 30123	Tape and Neel				
CT8132EK-IL4	-40 to 85	Omnipolar	Push-Pull	±70	±50	10 Hz	4-lead LGA	Tape and Reel				
CT8132EK-IS3	-40 to 85	Omnipolar	Push-Pull	±70	±50	10 Hz	3-lead SOT23	Tape and Reel				
CT8132EK-HS3	-40 to 125	Ommpolar	FuSII-FuII	110	130	10112	3-lead 30123	Tape and Neel				
CT8132SK-IL4	-40 to 85	Omnipolar	Push-Pull	±9	±5	10 Hz	4-lead LGA	Tape and Reel				
CT8132SK-HL4	-40 to 125	Omnipolar	Pusn-Pull	19	ΞĐ	10 HZ	4-lead LGA	Tape and Reel				
CT8132SK-IS3	-40 to 85	Omnipolar	Push-Pull	±9	±5	10 Hz	3-lead SOT23	Tape and Reel				
CT8132SK-HS3	-40 to 125	Ommpoiar	rusii-ruli	19	Ξΰ	10 112	3-18au 30123	Tape and Reel				
CT8132SL-IS3	-40 to 85	Omninolor	Push-Pull	±9	±5	250 Hz	3-lead SOT23	Topo and Basi				
CT8132SL-HS3	-40 to 125	Omnipolar	Pusii-Puli			250 円2	3-lead 50123	Tape and Reel				



# **Integrated Omnipolar TMR Digital Switches**

#### ABSOLUTE MAXIMUM RATINGS [1]

Characteristic	Symbol		Notes	Rating	Unit
Supply Voltage	V <sub>DD</sub>			-0.3 to 6.0	V
Push-Pull Output (Active Low)	V <sub>OUT_PP</sub>			-0.3 to V <sub>DD</sub> + 0.3 <sup>[2]</sup>	V
Open Drain Output (Active Low)	V <sub>OUT_OD</sub>			-0.3 to 6.0	V
Analog Input/Output Pins Maximum Voltage	V <sub>I/O</sub>			-0.3 to V <sub>DD</sub> + 0.3 [2]	V
Input and Output Current	I <sub>IN</sub> , I <sub>OUT</sub>			±20.0	mA
Maximum External Magnetic Field	В	T = 25°C	CT8132Sx	±600	G
Maximum External Magnetic Field	B <sub>MAX</sub>	$T_A = 25^{\circ}C$	CT813xBx, CT8132DM, CT8132EK	±2000	G
Cleatractatic Discharge Protection Level	ESD	Human Body I	Model (HBM) per JESD22-A114	±4.0 (min)	kV
Electrostatic Discharge Protection Level	ESD	Charged Devi	ce Model (CDM) per JESD22-C101	±0.5 (min)	kV
Junction Temperature	TJ			-40 to 150	°C
Storage Temperature	T <sub>STG</sub>			-65 to 155	°C
Lead Soldering Temperature	T <sub>L</sub>	10 seconds		260	°C

<sup>[1]</sup> Stresses exceeding the absolute maximum ratings may damage the CT813x and may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Allegro does not recommend exceeding or designing to absolute maximum ratings

#### **RECOMMENDED OPERATING CONDITIONS** [1]

Characteristic	Symbol	Notes	Min.	Тур.	Max.	Unit
Supply Voltage Range	V <sub>DD</sub>		1.7	3.3	5.5	V
Output Voltage Range	V <sub>OUT</sub>		0	_	$V_{DD}$	٧
Operating Magnetic Flux	B <sub>OP</sub>	CT8132Sx	_	_	±450	G
Output Current	I <sub>OUT</sub>		-	-	±3.0	mA
Bypass Capacitor	C <sub>BYP</sub>		-	1.0	-	μF
Operating Ambient Temperature	_	Industrial	-40	25	85	°C
<u>'</u>	I <sub>A</sub>	Extended Industrial	<del>-4</del> 0	25	125	°C

<sup>[1]</sup> The Recommended Operating Conditions table defines the conditions for actual operation of the CT813x. Recommended operating conditions are specified to ensure optimal performance to the specifications. Allegro does not recommend exceeding them or designing to absolute maximum ratings.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions	Value	Unit	
Junction-to-Ambient	$R_{ heta JA}$	Junction-to-ambient thermal resistance is a function of application and board layout and is determined in accordance to JEDEC standard JESD51 for a four (4) layer 2s2p FR-4 printed circuit board (PCB) with 2 oz. of copper (Cu) and	SOT23-3	202	°C/W
Thermal Resistance	T GJA	4 oz. of copper (Cu) or more for 65 A. Special attention must be paid not to exceed junction temperature T <sub>J(MAX)</sub> at a given ambient temperature T <sub>A</sub> .	SOT23-3 LGA-4	165	°C/W



 $<sup>^{[2]}\!</sup>$  The lower of  $V_{DD}$  + 0.3 V or 6.0 V.

#### **PINOUT DIAGRAMS AND TERMINAL LISTS**

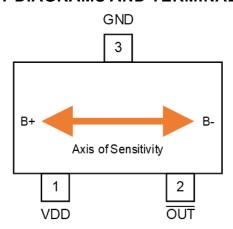


Figure 3: CT813x 3-Lead SOT23 Package for Digital Output (Top-Down View)

#### **Terminal List**

Number	Name	Function
1	VDD	Supply Voltage
2	OUT	Output Signal (Active Low)
3	GND	Ground

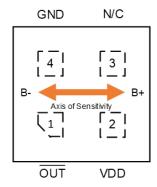


Figure 4: CT8131 4-Lead LGA Package with Digital Output (Top View)

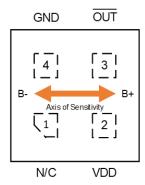


Figure 5: CT8132 4-Lead LGA Package with Digital Output (Top View)

#### **Terminal List**

Number	CT8131	CT8132	Function
1	OUT	NC	Output Signal for Open Drain (Active Low); N/C – No Connect
2	VDD	VDD	Supply Voltage
3	NC	OUT	Output Signal for Push-Pull (Active Low); N/C – No Connect
4	GND	GND	Ground



# **Integrated Omnipolar TMR Digital Switches**

**ELECTRICAL CHARACTERISTICS:** Valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  =  $-40^{\circ}$ C to 125 $^{\circ}$ C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25 $^{\circ}$ C, unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
PUSH-PULL OUTPUT						
Output Voltage High OUT [1]	V <sub>OH</sub>	I <sub>OUT</sub> = -2 mA	0.9 × V <sub>DD</sub>	-	_	V
Output Voltage Low OUT [1]	V <sub>OL</sub>	I <sub>OUT</sub> = 2 mA	_	_	0.1 × V <sub>DD</sub>	V
OPEN DRAIN OUTPUT						
Output Voltage High [1]	V <sub>OH</sub>		_	_	5.5	V
Output Voltage Low	V <sub>OL</sub>	I <sub>OUT</sub> ≤ 20 mA	0	_	0.5	V
High Output Leakage Current [1]	I <sub>LEAK</sub>	V <sub>OH</sub> = 5.5 V, B <sub>OP</sub> = 0	_	20	_	pА
TIMINGS						
Power-On Time [1]	t <sub>ON</sub>	V <sub>DD</sub> ≥ 1.7 V	_	50	75	μs
Active Mode Time [1]	t <sub>ACTIVE</sub>		_	2.6	_	μs
PROTECTION						
Lindow (altaga Lagica) t [1]		Rising V <sub>DD</sub>	_	1.60	1.64	V
Undervoltage Lockout [1]	V <sub>UVLO</sub>	Falling V <sub>DD</sub>	1.44	1.53	_	V
UVLO Hysteresis [1]	V <sub>UV_HYS</sub>		_	70	_	mV

<sup>[1]</sup> Guaranteed by design and characterization; not tested in production.

#### TYPICAL TIMING CHARACTERISTICS

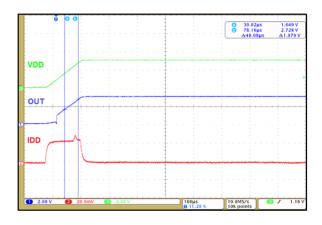


Figure 6: Power-On Time for Push-Pull Output

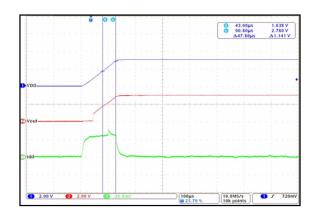


Figure 7: Power-On Time for Open Drain Output

# **Integrated Omnipolar TMR Digital Switches**

CT8131BV – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  =  $-40^{\circ}$ C to 125 $^{\circ}$ C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25 $^{\circ}$ C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	140	900	nA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	110	900	nA
Sampling Frequency	f <sub>S1</sub>		1	2	4	Hz
Idle Mode Time	t <sub>IDLE1</sub>	f <sub>S</sub> = 2 Hz	250	500	1000	ms
Operate Point, B+	B <sub>OPS</sub>		23	30	38	G
Operate Point, B-	B <sub>OPN</sub>		-38	-30	-23	G
Release Point, B+	B <sub>RPS</sub>		14	20	27	G
Release Point, B-	B <sub>RPN</sub>		-27	-20	-14	G
Hysteresis	B <sub>HYST</sub>		5	10	_	G

# CT8132BH – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for $V_{DD}$ = 1.7 to 5.5 V, $C_{BYP}$ = 1.0 $\mu$ F, and $T_A$ = -40°C to 125°C, typical values are $V_{DD}$ = 3.3 V and $T_A$ = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	45	57	μA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	41	47	μA
Sampling Frequency	f <sub>S</sub>		6	10	14	kHz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 10 kHz	71	100	167	μs
Operate Point, B+	B <sub>OPS</sub>		23	30	38	G
Operate Point, B-	B <sub>OPN</sub>		-38	-30	-23	G
Release Point, B+	B <sub>RPS</sub>		14	20	27	Ð
Release Point, B-	B <sub>RPN</sub>		-27	-20	-14	G
Hysteresis	B <sub>HYST</sub>		5	10	_	G



# **Integrated Omnipolar TMR Digital Switches**

CT8132BL – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  = -40°C to 125°C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25°C

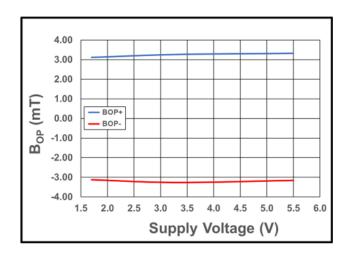
Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Cumply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	_	1.3	3.0	μΑ
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	-	1.1	2.0	μA
Sampling Frequency	f <sub>S</sub>		150	250	350	Hz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 250 Hz	2.8	4.0	6.7	ms
Operate Point, B+	B <sub>OPS</sub>		23	30	38	G
Operate Point, B-	B <sub>OPN</sub>		-38	-30	-23	G
Release Point, B+	B <sub>RPS</sub>		14	20	27	G
Release Point, B-	B <sub>RPN</sub>		-27	-20	-14	G
Hysteresis	B <sub>HYST</sub>		5	10	-	G

# CT8132BV – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for $V_{DD}$ = 1.7 to 5.5 V, $C_{BYP}$ = 1.0 $\mu$ F, and $T_A$ = -40°C to 125°C, typical values are $V_{DD}$ = 3.3 V and $T_A$ = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	140	900	nA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	110	700	nA
Sampling Frequency	f <sub>S</sub>		1	2	4	Hz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 2 Hz	250	500	1000	ms
Operate Point, B+	B <sub>OPS</sub>		23	30	38	G
Operate Point, B-	B <sub>OPN</sub>		-38	-30	-23	G
Release Point, B+	B <sub>RPS</sub>		14	20	27	G
Release Point, B-	B <sub>RPN</sub>		-27	-20	-14	G
Hysteresis	B <sub>HYST</sub>		5	10	_	G



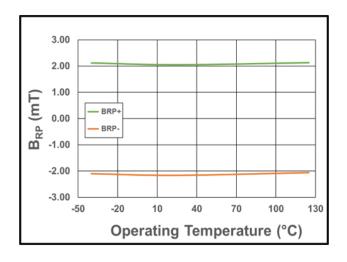
#### TYPICAL MAGNETIC CHARACTERISTICS FOR CT813xBV, CT8132BH AND CT8132BL



3.00 2.25 1.50 0.75 (mT) 0.00 -0.75 -1.50 -2.25 -3.002.0 2.5 3.5 4.5 5.0 3.0 4.0 5.5 6.0 Supply Voltage (V)

Figure 8:  $B_{OP-}$  (Red) and  $B_{OP+}$  (Blue) vs. Supply Voltage at  $T_{\Delta} = 25^{\circ}C$ 

Figure 9:  $B_{RP-}$  (Red) and  $B_{RP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C



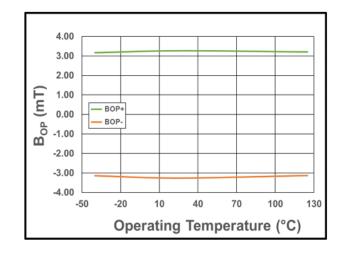


Figure 10:  $B_{OP-}$  (Orange) and  $B_{OP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

Figure 11:  $B_{RP-}$  (Orange) and  $B_{RP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT813xBV

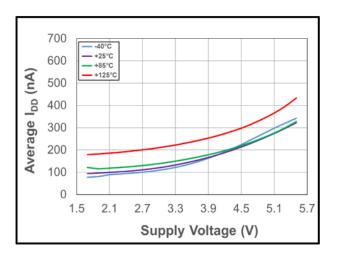


Figure 12: Average Supply Current vs. Supply Voltage vs. Temperature

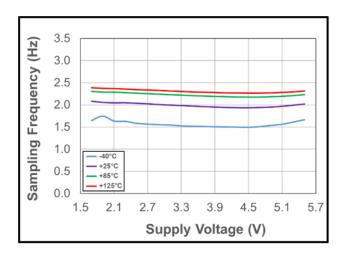


Figure 13: Average Supply Current vs. Temperature vs. Supply Voltage

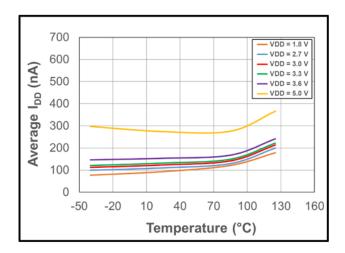


Figure 14: Sampling Frequency vs. Supply Voltage vs. Temperature



#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132BH

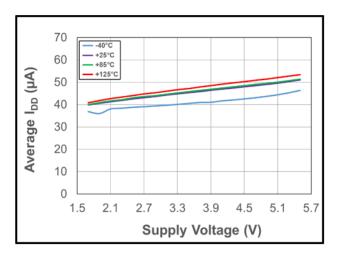


Figure 15: Average Supply Current vs. Supply Voltage vs. Temperature

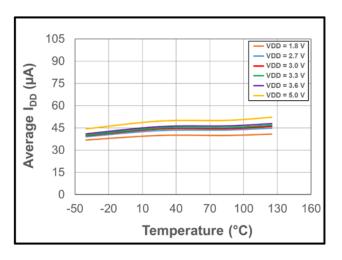


Figure 16: Average Supply Current vs. Temperature vs. Supply Voltage

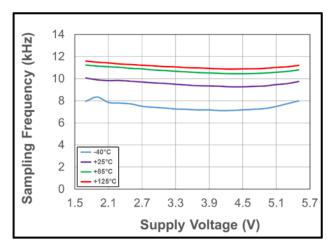


Figure 17: Sampling Frequency vs. Supply Voltage vs. Temperature



#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132BL

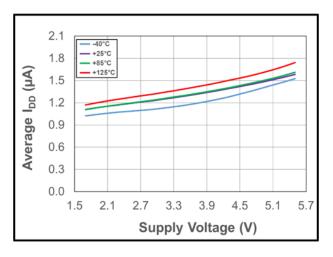


Figure 18: Average Supply Current vs. Supply Voltage vs. Temperature

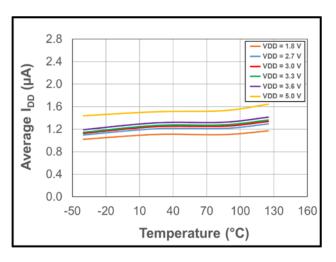


Figure 19: Average Supply Current vs. Temperature vs. Supply Voltage

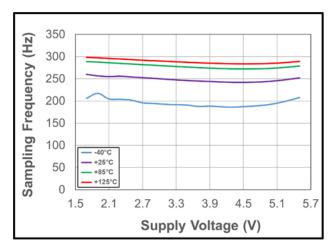


Figure 20: Sampling Frequency vs. Supply Voltage vs. Temperature



# **Integrated Omnipolar TMR Digital Switches**

CT8132DM – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  = -40°C to 125°C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	11.5	15.0	μA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	10.5	12.0	μA
Sampling Frequency	f <sub>S</sub>		1.5	2.5	3.5	kHz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 2.5 kHz	285	400	667	μs
Operate Point, B+	B <sub>OPS</sub>		11	15	19	G
Operate Point, B–	B <sub>OPN</sub>		-19	-15	-11	G
Release Point, B+	B <sub>RPS</sub>		6	10	14	G
Release Point, B-	B <sub>RPN</sub>		-14	-10	<del>-</del> 6	G
Hysteresis	B <sub>HYST</sub>		3	5	-	G



#### TYPICAL MAGNETIC CHARACTERISTICS FOR CT8132DM

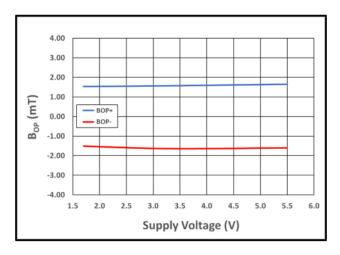


Figure 21:  $B_{OP-}$  (Red) and  $B_{OP+}$  (Blue) vs. Supply Voltage at  $T_{\Delta}$  = 25°C

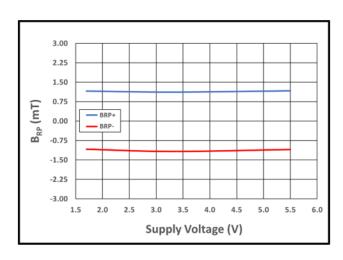


Figure 22:  $B_{RP-}$  (Red) and  $B_{RP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C

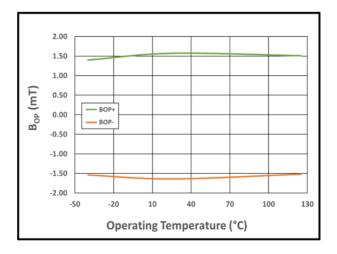


Figure 23:  $B_{OP-}$  (Orange) and  $B_{OP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

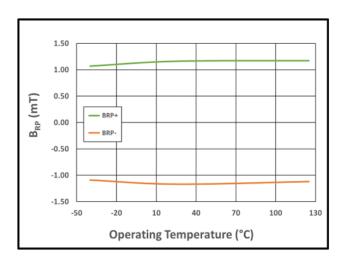


Figure 24:  $B_{RP-}$  (Orange) and  $B_{RP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132DM

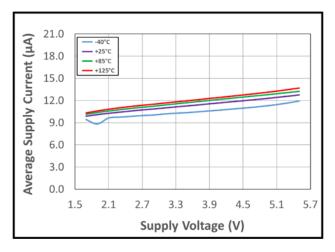


Figure 25: Average Supply Current vs. Supply Voltage vs. Temperature

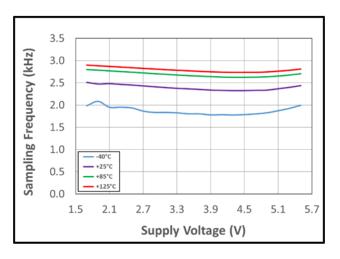


Figure 26: Average Supply Current vs. Temperature vs. Supply Voltage

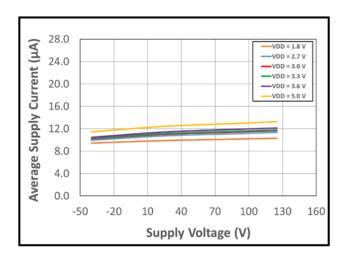


Figure 27: Sampling Frequency vs. Supply Voltage vs. Temperature



# **Integrated Omnipolar TMR Digital Switches**

CT8132EK – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  = -40°C to 125°C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25°C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	190	900	nA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	145	700	nA
Sampling Frequency	f <sub>S</sub>		6	10	14	Hz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 10 Hz	71	100	166	ms
Operate Point, B+	B <sub>OPS</sub>		62	70	78	G
Operate Point, B-	B <sub>OPN</sub>		-78	-70	-62	G
Release Point, B+	B <sub>RPS</sub>		42	50	60	G
Release Point, B-	B <sub>RPN</sub>		-60	-50	-42	G
Hysteresis	B <sub>HYST</sub>		12	20	-	G



#### TYPICAL MAGNETIC CHARACTERISTICS FOR CT8132EK

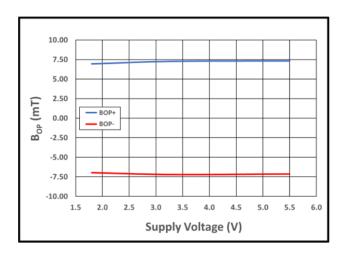


Figure 28:  $B_{OP-}$  (Red) and  $B_{OP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C

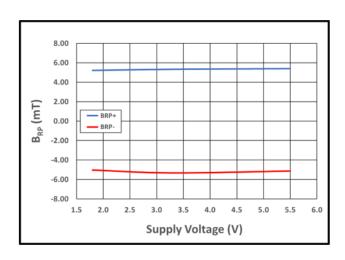


Figure 29:  $B_{RP-}$  (Red) and  $B_{RP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C

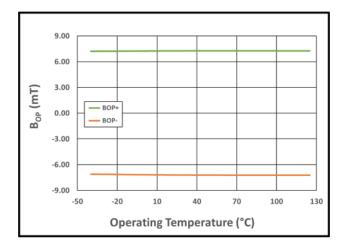


Figure 30:  $B_{OP-}$  (Orange) and  $B_{OP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

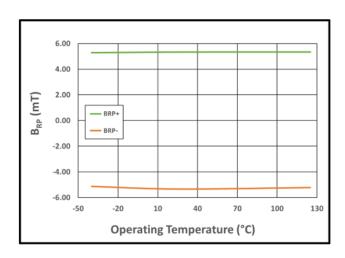


Figure 31:  $B_{RP-}$  (Orange) and  $B_{RP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132EK

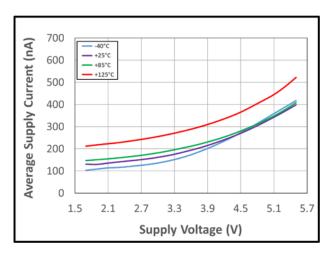


Figure 32: Average Supply Current vs. Supply Voltage vs. Temperature

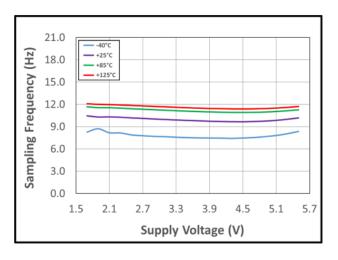


Figure 33: Average Supply Current vs. Temperature vs. Supply Voltage

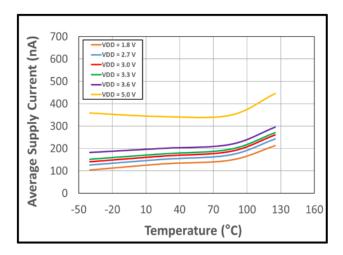


Figure 34: Sampling Frequency vs. Supply Voltage vs. Temperature



# **Integrated Omnipolar TMR Digital Switches**

CT8132SK – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for  $V_{DD}$  = 1.7 to 5.5 V,  $C_{BYP}$  = 1.0  $\mu$ F, and  $T_A$  =  $-40^{\circ}$ C to 125 $^{\circ}$ C, typical values are  $V_{DD}$  = 3.3 V and  $T_A$  = 25 $^{\circ}$ C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Average Supply Current	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	190	900	nA
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	_	145	700	nA
Sampling Frequency	f <sub>S</sub>		6	10	14	Hz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 10 Hz	71	100	166	ms
Operate Point, B+	B <sub>OPS</sub>		7	9	12	G
Operate Point, B-	B <sub>OPN</sub>		-12	<b>-</b> 9	<b>-</b> 7	G
Release Point, B+	B <sub>RPS</sub>		3	5	7	G
Release Point, B-	B <sub>RPN</sub>		-7	<b>-</b> 5	-3	G
Hysteresis	B <sub>HYST</sub>		3	4	_	G

# CT8132SL – ELECTRICAL CHARACTERISTICS and MAGNETIC SPECIFICATIONS: Uness otherwise specified, valid for $V_{DD}$ = 1.7 to 5.5 V, $C_{BYP}$ = 1.0 $\mu$ F, and $T_A$ = $-40^{\circ}$ C to 125 $^{\circ}$ C, typical values are $V_{DD}$ = 3.3 V and $T_A$ = 25 $^{\circ}$ C

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
	I <sub>DD(AVG)</sub>	t ≥ 10 seconds	-	1.3	3.0	μΑ
Average Supply Current	I <sub>DD(AVG)_1.8V</sub>	t ≥ 10 seconds, V <sub>DD</sub> = 1.8 V	-	1.1	2.0	μA
Sampling Frequency	f <sub>S</sub>		150	250	350	Hz
Idle Mode Time	t <sub>IDLE</sub>	f <sub>S</sub> = 250 Hz	2.8	4.0	6.7	ms
Operate Point, B+	B <sub>OPS</sub>		7	9	12	G
Operate Point, B-	B <sub>OPN</sub>		-12	<b>-</b> 9	<b>-</b> 7	G
Release Point, B+	B <sub>RPS</sub>		3	5	7	G
Release Point, B-	B <sub>RPN</sub>		-7	<b>-</b> 5	-3	G
Hysteresis	B <sub>HYST</sub>		3	4	_	G



#### TYPICAL MAGNETIC CHARACTERISTICS FOR CT8132SK AND CT8132SL

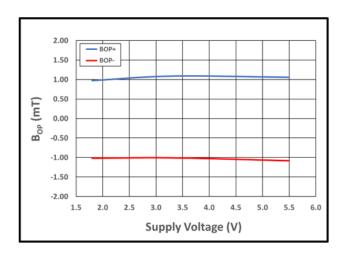


Figure 35:  $B_{OP-}$  (Red) and  $B_{OP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C

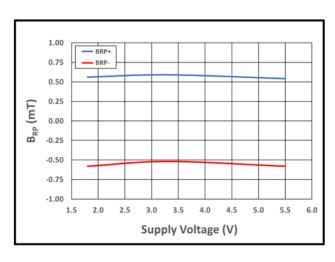


Figure 36:  $B_{RP-}$  (Red) and  $B_{RP+}$  (Blue) vs. Supply Voltage at  $T_A = 25$ °C

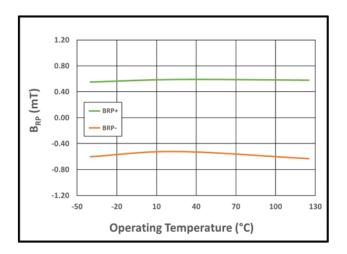


Figure 37:  $B_{OP-}$  (Orange) and  $B_{OP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

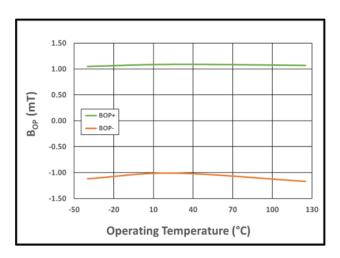


Figure 38:  $B_{RP-}$  (Orange) and  $B_{RP+}$  (Green) vs. Temperature at  $V_{DD}$  = 3.3 V

#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132SK

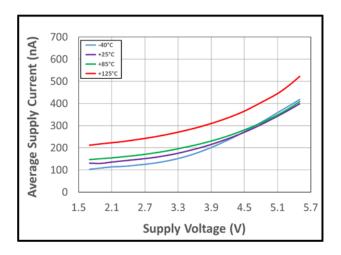


Figure 39: Average Supply Current vs. Supply Voltage vs. Temperature

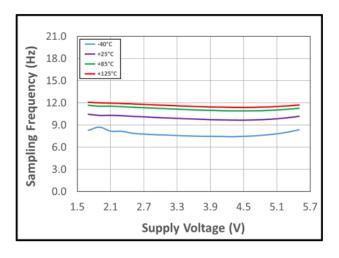


Figure 40: Average Supply Current vs. Temperature vs. Supply Voltage

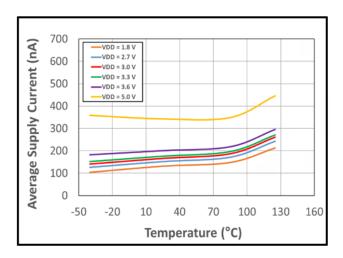
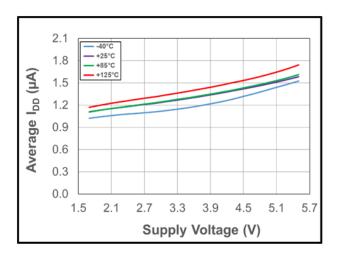


Figure 41: Sampling Frequency vs. Supply Voltage vs. Temperature



#### TYPICAL ELECTRICAL CHARACTERISTICS FOR CT8132SL



2.8 VDD = 2.7 V 2.4 VDD = 3.0 V Average I<sub>DD</sub> (µA) VDD = 3.3 V 2.0 VDD = 3.6 V VDD = 5.0 V 1.6 1.2 0.8 0.4 10 100 -50 -20 40 70 130 160 Temperature (°C)

Figure 42: Average Supply Current vs. Supply Voltage vs. Temperature

Figure 43: Average Supply Current vs. Temperature vs. Supply Voltage

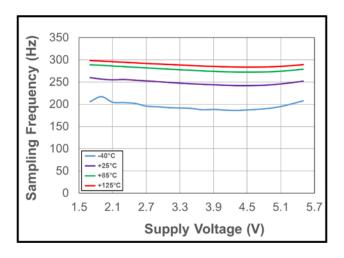


Figure 44: Sampling Frequency vs. Supply Voltage vs. Temperature



#### **FUNCTIONAL DESCRIPTION**

#### Overview

The CT813x is a product family of omnipolar TMR magnetic switches that supports a wide operating voltage range of 1.7 to 5.5 V and is capable of providing two digital output configurations: open drain or push-pull. These omnipolar TMR digital switches are designed to consume a minimal amount of current which is ideal for battery-operated products. It also supports a wide range of sensitivity levels for various applications.

#### **Undervoltage Lockout (UVLO)**

The Undervoltage Lockout protection circuitry of the CT813x is activated when the supply voltage ( $V_{DD}$ ) falls below 1.53 V. The CT813x remains in a low quiescent state and the  $\overline{OUT}$  output is not valid until  $V_{DD}$  rises above the UVLO threshold (1.60 V).

### Power-On Time (t<sub>ON</sub>)

The Power-On Time ( $t_{ON}$ ) of 50  $\mu s$  is the amount of time required by the CT813x to start up, power-on, and acquire the first sample. The chip is fully powered up and operational from the moment the supply voltage passes the rising UVLO point (1.60 V). This time includes the ramp-up time and the settling time (within 10% of steady-state voltage under an applied magnetic field) after the power supply have reach the minimum  $V_{DD}$ .

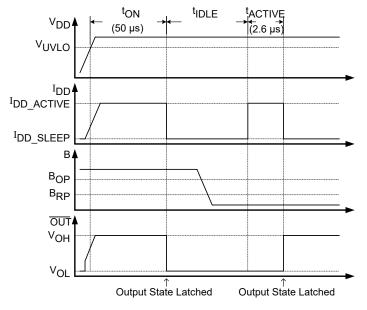


Figure 45: CT813x Power-On Timing Diagram

#### **Omnipolar Magnetic Flux**

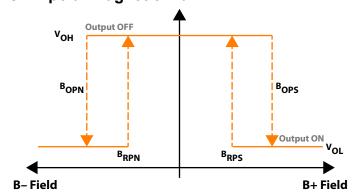


Figure 46: CT813x Response Time Curve

Table 1: CT8131 Open Drain Output Behavior

Magnetic Field	Condition	Output
Positive Field	B > B <sub>OPS</sub>	Low (ON)
	0 < B < B <sub>RPS</sub>	High-Z (OFF)
Negative Field	B < B <sub>OPN</sub>	Low (ON)
	0 > B > B <sub>RPN</sub>	High-Z (OFF)

Table 2: CT8132 Push-Pull Output Behavior

• • • • • • • • • • • • • • • • • • •						
Magnetic Field	Condition	Output				
Positive Field	B > B <sub>OPS</sub>	Low (ON)				
	0 < B < B <sub>RPS</sub>	High (OFF)				
Negative Field	B < B <sub>OPN</sub>	Low (ON)				
	0 > B > B <sub>RPN</sub>	High (OFF)				



#### **APPLICATIONS INFORMATION**

A decoupling capacitor,  $C_{BYP}$ , between the supply voltage (VDD) and ground (GND) is required to lower the noise going into the CT8131 as well as providing isolation from the other circuits. The decoupling capacitor should be placed close to the TMR digital switch. A typical capacitor value of 1.0  $\mu$ F (ceramic) will be sufficient. A pull-up resistor of 47 k $\Omega$  connected from OUT to the system voltage ( $V_{SYS}$ ) is required for the CT8131.

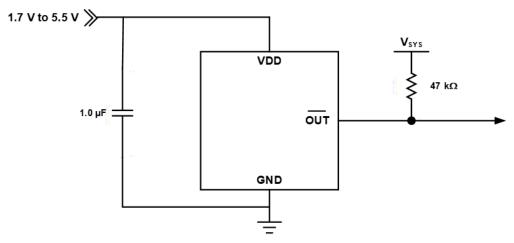


Figure 47: CT8131 Application Block Diagram

Like the CT8131, the CT8132 products require a  $1.0~\mu F$  (ceramic) bypass capacitor to be connected between the supply voltage and ground.

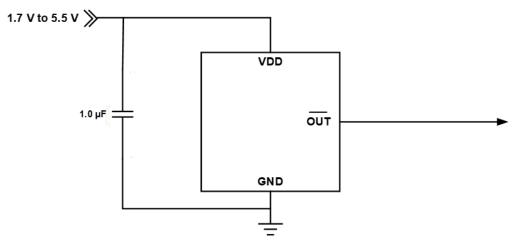


Figure 48: CT8132 Application Block Diagram



# **Integrated Omnipolar TMR Digital Switches**

#### **XtremeSense TMR Current Sensor Location**

The XtremeSense TMR sensor location for the CT813x products are shown in Figure 49 and Figure 50. The dimensions shown in both figures are typical values.

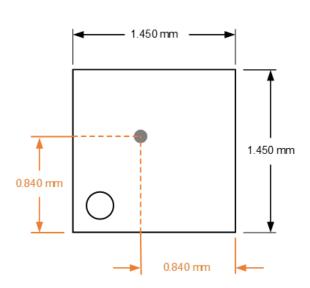


Figure 49: XtremeSense TMR Sensor Location for CT813x products in 3-lead SOT23 Package

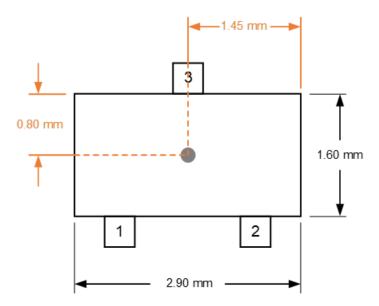


Figure 50: XtremeSense TMR Sensor Location for CT813x products in 4-lead LGA Package



#### **PACKAGE OUTLINE DRAWINGS**

#### For Reference Only - Not for Tooling Use

Dimensions in millimeters - NOT TO SCALE

Dimensions exclusive of mold flash, gate burs, and dambar protrusions Exact case and lead configuration at supplier discretion within limits shown

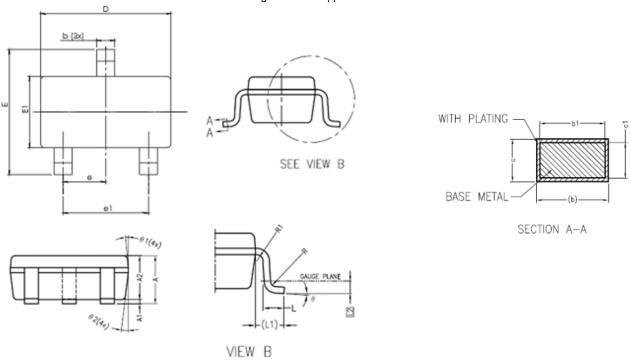


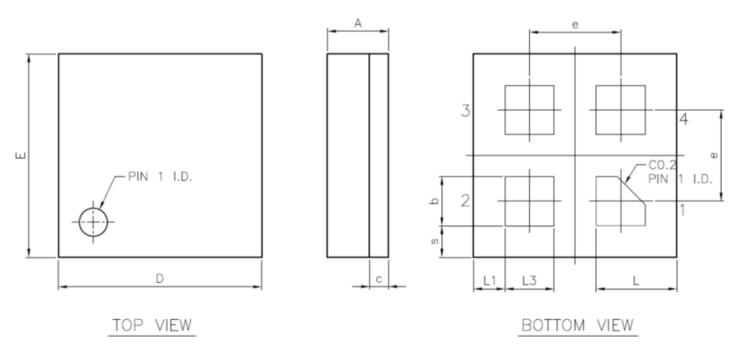
Figure 51: 3-Lead SOT23 Package Drawing

Table 3: CT813x 3-Lead SOT23 Package Dimensions

Symple of	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
А	1.05	1.20	1.35			
A1	0.00	0.10	0.15			
A2	A2 1.00		1.20			
b	0.30	_	0.50			
b1	0.30	0.35	0.45			
С	0.08	_	0.22			
c1	0.08	0.13	0.20			
D	2.80	2.90	3.00			
E	2.60	2.80	3.00			
E1	1.50	1.60	1.70			

Sumb al	Dimensions in Millimeters (mm)					
Symbol	Min. Typ.		Max.			
е		0.95 BSC				
e1		1.90 BSC				
L	0.35	0.35 0.43 0.6				
L1		0.50 REF				
L2		0.25 BSC				
R	0.10	_	_			
R1	0.10	_	0.25			
θ	0°	0° 4° 8°				
θ1	5°	15°				
θ2	5°	8°	15°			





#### NOTES:

- 1. All dimensions are in millimeters.
- 2. Pin A1 ID is marked by ink or laser.

Figure 52: 4-Lead LGA Package Drawing

Table 4: CT813x 4-Lead LGA Package Dimensions

Symbol	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
A	0.386	0.436	0.486			
b	0.300	0.350	0.400			
С	c – 0.136 REF		_			
D	1.400	1.450	1.500			
E	1.400	1.450	1.500			
е	_	0.650	_			
L	0.525	0.575	0.625			
L1	0.175	0.225	0.275			
L3	0.300	0.350	0.400			
s	0.175	0.225	0.275			

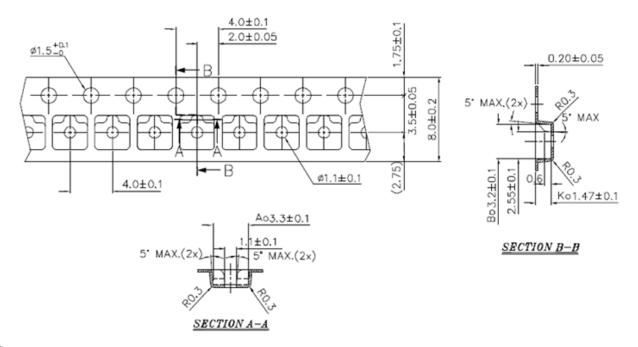
#### TAPE AND REEL POCKET DRAWINGS AND DIMENSIONS

#### For Reference Only - Not for Tooling Use

Dimensions in millimeters – NOT TO SCALE

Dimensions exclusive of mold flash, gate burs, and dambar protrusions

Exact case and lead configuration at supplier discretion within limits shown



#### NOTES:

- 1. Material: Conductive Polystyrene.
- 2. Dimensions in mm.
- 3. 10 sprocket hole pitch cumulative tolerance  $\pm 0.20$  mm.
- 4. Camber not to exceed 1 mm in 100 mm.
- 5. Pocket position relative to sprocket hole measured as true position of pocket and not pocket hole.
- 6. (S.R.  $\Omega$ /sq) means surface electric resistivity of the carrier tape.

Figure 53: Tape and Pocket Drawing for 3-lead SOT23 Package

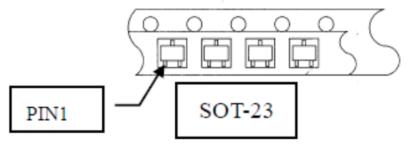


Figure 54: SOT23 Orientation in Tape Pocket



### **Integrated Omnipolar TMR Digital Switches**

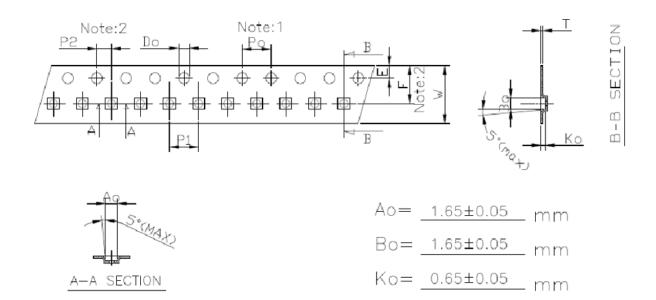


Figure 55: Tape and Pocket Drawing for LGA-4 Package

**Table 5: LGA-4 Tape and Pocket Dimensions** 

Symbol	Specification
Po	4.00 mm ± 0.10 mm
P1	4.00 mm ± 0.10 mm
P2	2.00 mm ± 0.05 mm
Do	1.50 mm ± 0.10 mm
D1	1.10 mm ± 0.05 mm
E	1.75 mm ± 0.10 mm
F	3.50 mm ± 0.05 mm
10Po	40.00 mm ± 0.10 mm
W	8.00 mm ± 0.20 mm
Т	0.25 mm ± 0.02 mm

#### NOTES:

- 1. 10 sprocket hole pitch cumulative tolerance is  $\pm 0.10$  mm.
- 2. Pocket position is relative to sprocket hole measured as true position of pocket and not pocket hole.
- 3. Ao and Bo measured on a place of 0.3 mm above the bottom of the pocket to top surface of the carrier.
- 4. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 5. Carrier camber shall not more than 1 mm per 100 mm through a length of 250 mm.



# **Integrated Omnipolar TMR Digital Switches**

#### **PACKAGE INFORMATION**

Table 6: CT813x Package Information

Part Number	Package Type	# of Leads	Package Quantity	Lead Finish	Eco Plan [1]	MSL Rating [2]	Operating Temperature (°C) [3]	Device Marking <sup>[4]</sup>
CT8131BV-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	L YZ
CT8131BV-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	L YZ
CT8131BV-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	JD YWWS
CT8131BV-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	JD YWWS
CT8132BH-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	G YZ
CT8132BH-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	G YZ
CT8132BH-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MG YWWS
CT8132BH-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MG YWWS
CT8132BL-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MB YWWS
CT8132BL-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MB YWWS
CT8132BV-IL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 85	M YZ
CT8132BV-HL4	LGA	4	3000	Sn	Green & RoHS	3	-40 to 125	M YZ
CT8132BV-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MAYWWS
CT8132BV-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MAYWWS
CT8132DM-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MD YWWS
CT8132DM-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MD YWWS
CT8132EK-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MF YWWS
CT8132EK-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MF YWWS
CT8132SK-IL4	LGA	4	3000	Au	Green & RoHS	3	-40 to 85	P YZ U YZ
CT8132SK-HL4	LGA	4	3000	Au	Green & RoHS	3	-40 to 125	V YZ X YZ
CT8132SK-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	MC YWWS
CT8132SK-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	MC YWWS
CT8132SL-IS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 85	ME YWWS
CT8132SL-HS3	SOT23	3	3000	Sn	Green & RoHS	1	-40 to 125	ME YWWS

<sup>[1]</sup> RoHS is defined as semiconductor products that are compliant to the current EU RoHS requirements. It also will meet the requirement that RoHS substances do not exceed 0.1% by weight in homogeneous materials. Green is defined as the content of chlorine (CI), bromine (Br), and antimony trioxide based flame retardants satisfy JS709B low halogen requirements of ≤ 1,000 ppm.



<sup>[2]</sup> MSL Rating = Moisture Sensitivity Level Rating as defined by JEDEC standard classifications.

<sup>[3]</sup> Package will withstand ambient temperature range of -40°C to 150°C and storage temperature range of -65°C to 150°C.

<sup>[4]</sup> Device Marking for SOT23 is defined as XZ YWWS where XZ = part number nominator, Y = year, WW = work week, and S = sequential number. LGA is defined as X where X = part number nominator and YZ = date code information.

### **Integrated Omnipolar TMR Digital Switches**

#### **Revision History**

Number	Date	Description
1	December 11, 2023	Document rebranded and minor editorial updates
2	February 29, 2024	Updated Selection Guide (page 2)
3	March 22, 2024	Updated Operate Point and Hysteresis values for CT8132SK (page 18)
4	May 14, 2024	Changed "latch(es)" to "switch(es)"
5	June 5, 2024	Added notes to package drawings (pages 25 and 27)
6	March 20, 2025	Added product variant CT8132EK-IL4 to the Selection Guide (page 2), updated power-on timing and response time curve diagrams (page 22), and reformatted document as an interactive PDF (all pages).

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